TLP714F

1. Applications

- Intelligent Power Module Signal Isolation
- Factory Automation (FA)
- Industrial Inverters

2. General

The TLP714F is a photocoupler in a 6-pin SDIP package that consists of a GaAtAs infrared light-emitting diode (LED) optically coupled to an integrated high-gain, high-speed photodetector IC chip. It provides guaranteed performance and specifications at temperatures up to 125° C. The TLP714F is physically smaller than the one in an 8-pin DIP package and compliant with international safety standards for reinforced insulation. It thus provides a smaller footprint solution for applications that require safety standard certification. An internal noise shield provides a guaranteed commonmode transient immunity of ± 20 kV/µs. The TLP714F guarantees minimum and maximum of propagation delay time, pulse width distortion. Therefore it is suitable for isolation interface between IPM and control IC circuits in motor control application. Leads of the TLP714F is bend to satisfy 8 mm PC board spacing requirements. Absolute maximum ratings and electrical characteristics are the same as in the TLP714.

3. Features

- (1) Inverter logic type (open collector output)
- (2) Package: SDIP6
- (3) Operating temperature: -40 to 125°C
- (4) Supply voltage: -0.5 to 30 V
- (5) Threshold input current: 5.0 mA (max)
- (6) Supply current: 1.3 mA (max)
- (7) Propagation delay time: $t_{pHL} = 400 \text{ ns} \text{ (max)}, t_{pLH} = 550 \text{ ns} \text{ (max)}$
- (8) Pulse width distortion: 400 ns (max)
- (9) Common-mode transient immunity: ±20 kV/µs (min)
- (10) Isolation voltage: 5000 Vrms (min)
- (11) Safety standards

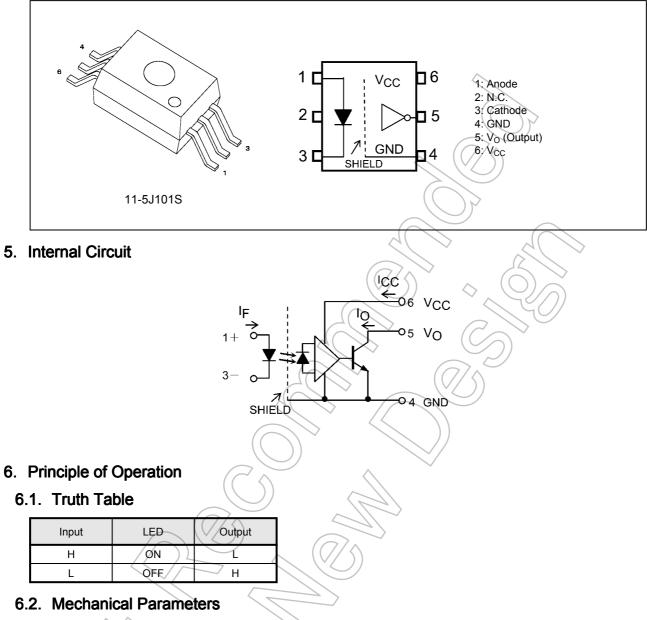
UL-approved: UL1577, File No.E67349

cUL-approved: CSA Component Acceptance Service No.5A File No.E67349

VDE-approved: EN60747-5-5 (Note 1)

Note 1: When an EN60747-5-5 approved type is needed, please designate the Option (D4).

4. Packaging and Pin Configuration



Characteristics	7.62-mm Pitch TLP714	10.16-mm Pitch TLP714F	Unit
Creepage distances	7.0 (min)	8.0 (min)	mm
Clearance distances	7.0 (min)	8.0 (min)	
Internal isolation thickness	0.4 (min)	0.4 (min)	
	$\langle \rangle \langle \rangle$		

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25^{\circ}$ C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		١ _F		20	mA
	Input forward current derating	$(T_a \ge 116^{\circ}C)$	$\Delta I_F / \Delta T_a$		-0.6	mA/°C
	Input forward current (pulsed)		I _{FP}	(Note 1)	50	mA
	Input forward current derating (pulsed)	$(T_a \ge 110^{\circ}C)$	$\Delta I_{FP} / \Delta T_a$		-1.25	mA/°C
	Input power dissipation		PD	(40	mW
	Input power dissipation derating	$(T_a \ge 110^{\circ}C)$	$\Delta P_D / \Delta T_a$	(/	-1.0	mW/°C
	Input reverse voltage		V _R		5	V
Detector	Output current		I ₀ ((\sum	15	mA
	Output voltage		Vo	\sum	-0.5 to 30	V
	Supply voltage		Vcc	\geq	-0.5 to 30	
	Output power dissipation		Po	~	80	mW
	Output power dissipation derating	$(T_a \ge 110^{\circ}C)$	$\Delta P_0 / \Delta T_a$	\diamond	-2.0	mW/°C
Common	Operating temperature		T _{opr}	4	-40 to 125	°C
	Storage temperature		∕ T _{stg}	\mathcal{C}	-55 to 150	
	Lead soldering temperature	(10 s)	T _{sol}	C	260	
	Isolation voltage	AC, 60 s, R.H. ≤ 60%	BVS	(Note 2)	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

8. Recommended Operating Conditions (Note)

Characteristics	$\langle \rangle$	Symbol	Note	Min	Тур.	Max	Unit
Input on-state current		I _{F(ON)}	(Note 1)	7.5	_	15	mA
Input off-state voltage		V _{F(OFF)}		0	_	0.8	V
Supply voltage	(7	V _{CC}	(Note 2)	4.5	_	30	
Operating temperature	1	T _{opr}	(Note 2)	-40	_	125	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this datasheet should also be considered.

Note: A ceramic capacitor (0.1 µF) should be connected between pin 6 and pin 4 to stabilize the operation of a highgain linear amplifier. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

Note 1: The rise and fall times of the input on-current should be less than 0.5 $\mu s.$

Note 2: Denotes the operating range, not the recommended operating condition.

Note 1: Pulse width (PW) \leq 1 ms, duty = 50%

9. Electrical Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125°C, $V_{CC} = 4.5$ to 30 V)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input forward voltage	V _F		_	I _F = 10 mA, T _a = 25°C	1.45	1.55	1.7	V
Input forward voltage temperature coefficient	$\Delta V_F / \Delta T_a$		—	I _F = 10 mA	~	-2.0	—	mV/°C
Input reverse current	I _R		_	V _R = 5 V, T _a = 25°C			10	μA
Input capacitance	Ct		_	V = 0 V, f = 1 MHz	ſĘ	60	—	pF
High-level output current	I _{ОН}		Fig. 12.1.1	$V_{\rm F}$ = 0.8 V, $V_{\rm O}$ < $V_{\rm CC}$		2_	50	μA
Low-level output voltage	V _{OL}		Fig. 12.1.2	I _F = 10 mA, I _O = 2.4 mA	$\left(\left(\right) \right)$	0.2	0.6	V
High-level supply current	I _{CCH}		Fig. 12.1.3	I _F = 0 mA	2	1.0	1.3	mA
Low-level supply current	I _{CCL}		Fig. 12.1.4	I _F = 10 mA	> -	1.0	1.3	
Output current	Ι _Ο		Fig. 12.1.5	I _F = 10 mA, V _O = 0.6 V	4.0		_	
Threshold input current (H/L)	I _{FHL}		_	l _O = 0.75 mA, V _O < 0.8 V	_	1.0	5.0	
Threshold input voltage (L/H)	V _{FLH}		_	l _O = 0.75 mA, V _O > 2.0 V	0.8	17	\geq	V

Note: All typical values are at $T_a = 25^{\circ}C$.

10. Isolation Characteristics (Unless otherwise specified, $T_a = 25^{\circ}$ C)

Characteristics	Symbol	Note Test Conditions		Min	Тур.	Max	Unit
Total capacitance (input to output)	CS	(Note 1)	V _S = 0 V, f = 1 MHz		0.8		pF
Isolation resistance	R _S	(Note 1)	V _S = 500 V, R.H. ≤ 60%	1 × 1012	1014		Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	5000	—	_	Vrms
			AC, 1 s in oil	\	10000		
		\bigcirc	DC, 60 s in oil) —	10000	_	Vdc

Note 1: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

11. Switching Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125°C, V_{CC} = 15 V)

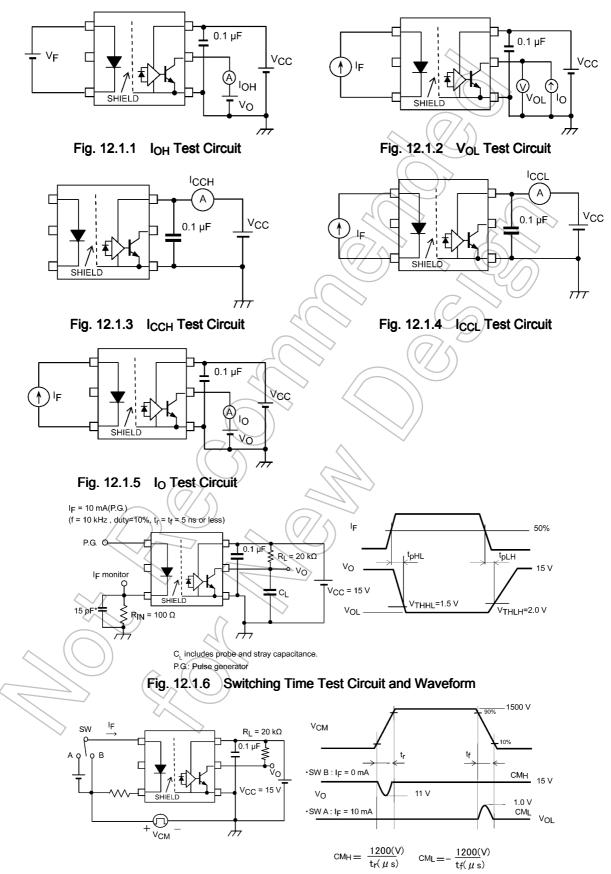
Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (H/L)	tpHL	(Note 1)	Fig. 12.1.6	$I_F = 0 \rightarrow 10 \text{ mA}, \text{ R}_L = 20 \text{ k}\Omega,$ $C_L = 100 \text{ pF}$	30	150	400	ns
	\bigcirc	/		$I_F = 0 \rightarrow 10 \text{ mA}, \text{ R}_L = 20 \text{ k}\Omega,$ $C_L = 10 \text{ pF}$	_	70	Ι	
Propagation delay time (L/H)	t _{pLH}	(Note 1)	\searrow	$\begin{array}{l} I_{\text{F}} = 10 \rightarrow 0 \text{ mA}, \text{ R}_{\text{L}} = 20 \text{ k}\Omega, \\ C_{\text{L}} = 100 \text{ pF} \end{array}$	150	350	550	
				$\begin{array}{l} I_{F} = 10 \rightarrow 0 \text{ mA}, R_{L} = 20 \; k\Omega, \\ C_{L} = 10 \; pF \end{array}$	_	110		
Pulse width distortion	t _{pHL} - t _{pLH}	(Note 1)		I _F = 10 mA, R _L = 20 kΩ, C _L = 100 pF	_	_	400	
Propagation delay skew (device to device)	t _{psk}	(Note 1), (Note 2)			-50		450	
Common-mode transient immunity at output high	СМ _Н	7	Fig. 12.1.7	$V_{CM} = 1500 V_{p-p}, I_F = 0 mA, R_L = 20 k\Omega, T_a = 25^{\circ}C, C_L = 10 pF or 100 pF$	±20	±25		kV/μs
Common-mode transient immunity at output low	CML				±20	±25	_	

Note: All typical values are at $T_a = 25^{\circ}C$.

Note 1: Input signal (f = 10 kHz, duty = 10%, input current t_r = t_f = 5 ns or less)

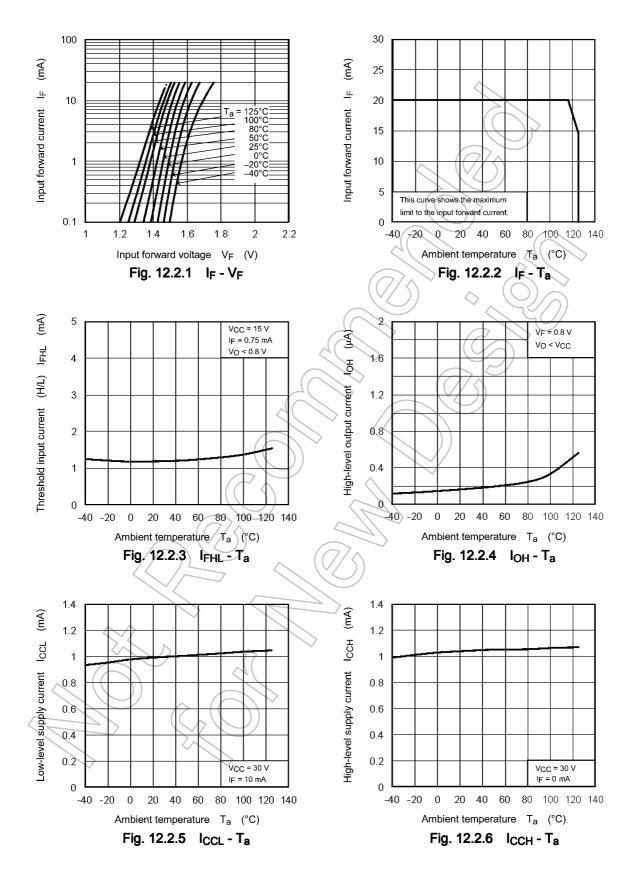
Note 2: The propagation delay skew, t_{psk} , is defined as the propagation delay time of the largest or smallest t_{pLH} minus the largest or smallest t_{pHL} of multiple samples. Evaluations of these samples are conducted under identical test conditions (supply voltage, input current, temperature, etc).

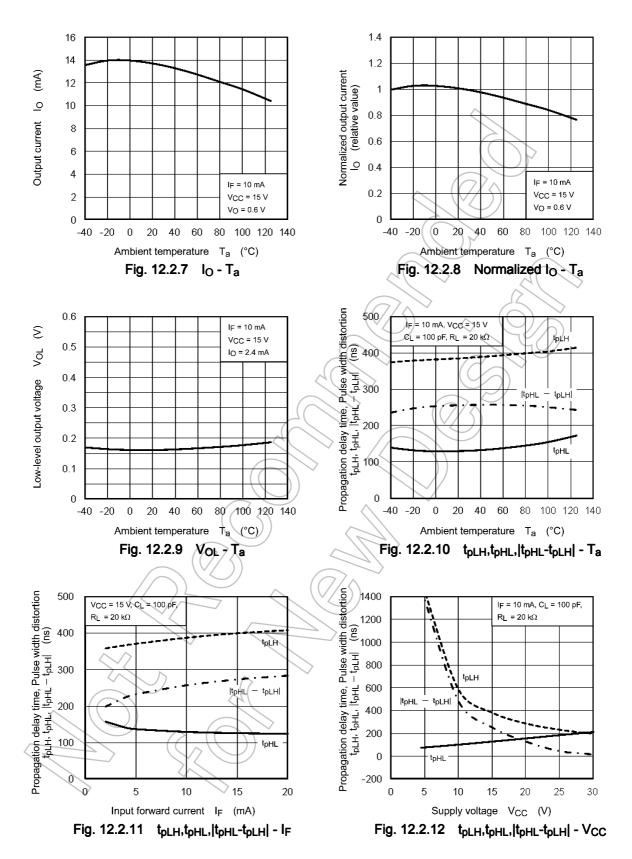
- 12. Test Circuits and Characteristics Curves
 - 12.1. Test Circuits

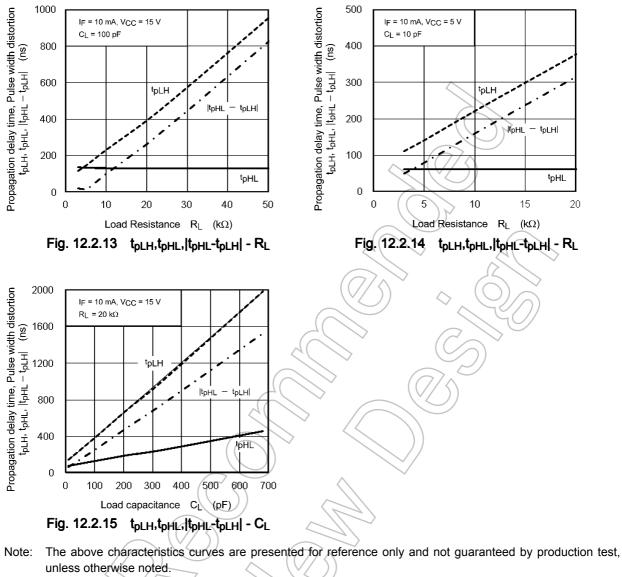




12.2. Characteristics Curves (Note)







13. Soldering and Storage

13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

- When using soldering reflow.
 - The soldering temperature profile is based on the package surface temperature.
 - (See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

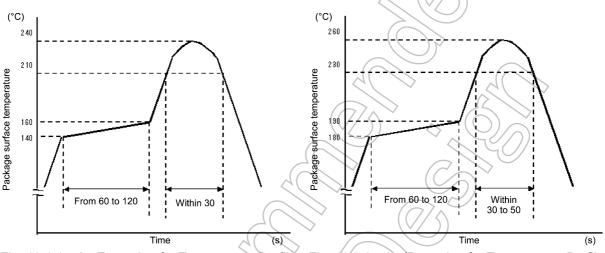


Fig. 13.1.1 An Example of a Temperature Profile Fig. 13.1.2 An Example of a Temperature Profile When Sn-Pb Eutectic Solder Is Used When Lead(Pb)-free Solder Is Used

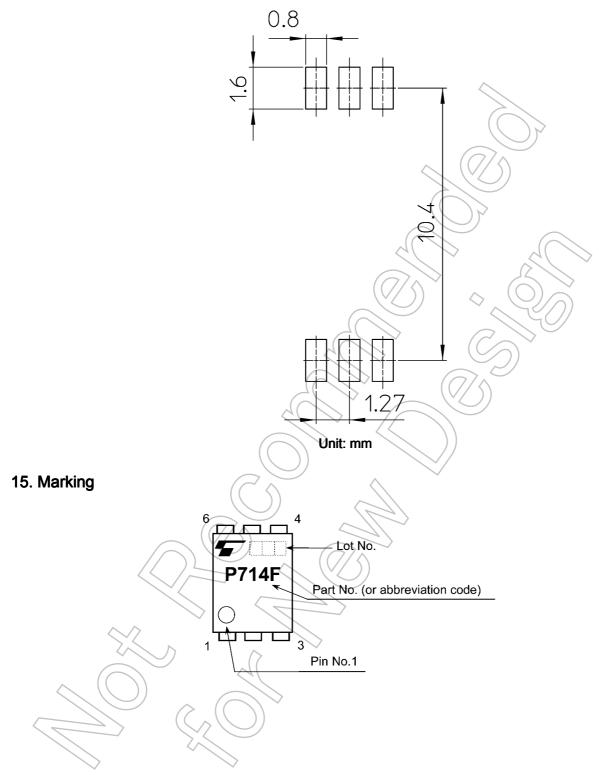
- When using soldering flow (Applicable to both eutectic solder and Lead(Pb)-Free solder) Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 °C within 10 seconds is recommended.
- Flow soldering must be performed once.
- When using soldering Iron Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

Heating by soldering iron must be done only once per lead.

13.2. Precautions for General Storage

- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- \cdot $\,$ When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

14. Land Pattern Dimensions for Reference Only



16. EN60747-5-5 Option (D4) Specification

- Part number: TLP714, TLP714F (Note 1)
 - The following part naming conventions are used for the devices that have been qualified according to option (D4) of EN60747.

Example: TLP714(D4-TP, F)

D4: EN60747 option

TP: Tape type

F: [[G]]/RoHS COMPATIBLE (Note 2)

Note 1: Use TOSHIBA standard type number for safety standard application. e.g., TLP714(D4-TP,F) \rightarrow TLP714

Note 2: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

Description	$(\mathbb{Z})^{\sim}$	Symbol	Rating	Unit
Application classification				
for rated mains voltage \leq 300 Vrms for rated mains voltage \leq 600 Vrms		\mathcal{O}	I-IV I-III	-
Climatic classification		\mathbb{Z}	40 / 125 / 21	_
Pollution degree			2	_
	TLPxxx type	/	890	Vpeak
Maximum operating insulation voltage	TLPxxxF type	VIORM	1140	
Input to output test voltage, Method A	TLPxxx type		1424	
$V_{pr} = 1.6 \times V_{IORM}$, type and sample test $t_p = 10$ s, partial discharge < 5 pC	TLPxxxF type	Vpr	1824	Vpeak
Input to output test voltage, Method B $V_{pr} = 1.875 \times V_{IORM}$, 100 % production test	TLPxxx type		1670	Vpeal
$t_p = 1 \text{ s, partial discharge} < 5 \text{ pC}$	TLPxxxF type	Vpr	2140	vpea
Highest permissible overvoltage (transient overvoltage, t _{pr} = 60 s)		V _{TR}	8000	Vpeal
Safety limiting values (max. permissible ratings in case also refer to thermal derating of				
current (input current $I_{P_r} P_{SO} = 0$)		l _{si}	300	mA
power (output or total power dissipation)		P _{so}	700	mW
temperature		Ts	150	°C
Insulation resistance $V_{IO} = 500 \text{ V}, \text{ T}_{a} = 25 \text{ °C}$			≥ 10 ¹²	
$V_{IO} = 500 \text{ V}, \text{ T}_{a} = 100 ^{\circ}$		R _{si}	$\geq 10^{11}$	Ω
$V_{IO} = 500 \text{ V}, \text{ T}_{a} = \text{T}_{s}$			≥ 10 ⁹	

Fig. 16.1 EN60747 Isolation Characteristics

		7.62-mm pitch TLPxxx type	10.16-mm pitch TLPxxxF type	
Minimum creepage distance	Cr	7.0 mm	8.0 mm	
Minimum clearance	CI	7.0 mm	8.0 mm	
Minimum insulation thickness	ti	0.4 mm		
Comparative tracking index	СТІ	175	5	

Fig. 16.2 Insulation Related Specifications (Note)

- Note: If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. (e. g., at a standard distance between soldering eye centers of 7.5 mm). If this is not permissible, the user shall take suitable measures.
- Note: This photocoupler is suitable for **safe electrical isolation** only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.

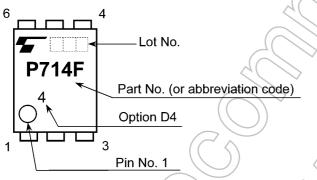
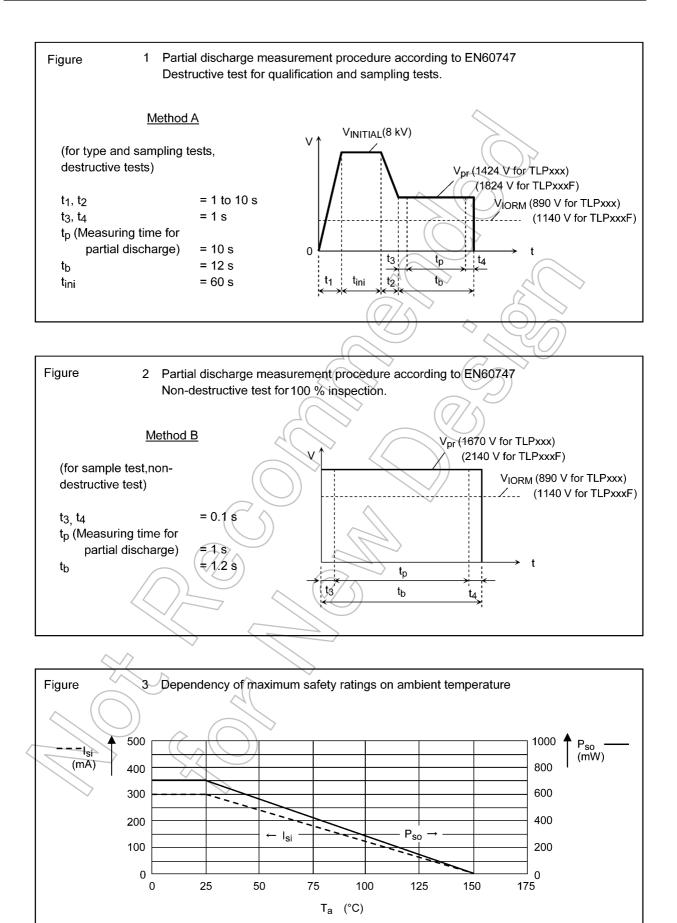
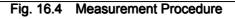


Fig. 16.3 Marking Example (Note)

Note: The above marking is applied to the photocouplers that have been qualified according to option (D4) of EN60747.



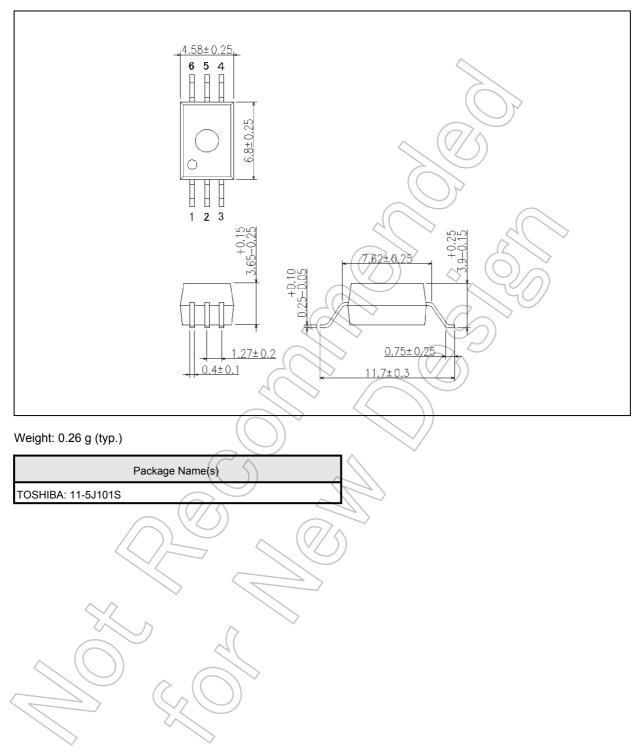




Package Dimensions

TLP714F

Unit: mm



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